

Silicon RF Switching Diode

- Low-loss VHF / UHF switch above 10 MHz
- PIN diode with low forward resistance
- Pb-free (RoHS compliant) package





BAT18-04

BAT18-05





Туре	Package	Configuration	L_S (nH)	Marking
BAT18-04	SOT23	series	1.8	AUs
BAT18-05	SOT23	common cathode	1.8	ASs

Maximum Ratings at $T_A = 25^{\circ}$ C, unless otherwise specified

Parameter	Symbol	Value	Unit
Diode reverse voltage	V _R	35	V
Forward current	/ _F	100	mA
Junction temperature	T _i	150	°C
Operating temperature range		-55 125	
Storage temperature	T _{stg}	-55 150	

Thermal Resistance

Parameter	Symbol	Value	Unit
Junction - soldering point ¹⁾	R _{thJS}	≤ 290	K/W
BAT18-04, BAT18-05			

¹For calculation of R_{thJA} please refer to Application Note Thermal Resistance



Parameter	Symbol	Values		Unit		
		min.	typ.	max.		
DC Characteristics				-		
Reverse current	I _R				nA	
V _R = 20 V		-	-	20		
$V_{\rm R}$ = 20 V, $T_{\rm A}$ = 60 °C		-	-	200		
Forward voltage	V _F	-	0.92	1.2	V	
<i>I</i> _F = 100 mA						
AC Characteristics						
Diode capacitance	CT	-	0.75	1	pF	
V _R = 20 V, <i>f</i> = 1 MHz						
Forward resistance	r _f	-	0.4	0.7	Ω	
<i>I</i> _F = 5 mA, <i>f</i> = 100 MHz						
Charge carrier life time	τ _{rr}	-	120	-	ns	
$I_{\rm F}$ = 10 mA, $I_{\rm R}$ = 6 mA, measured at $I_{\rm R}$ = 3 mA ,						
<i>R</i> _L = 100 Ω						
I-region width	W	-	3	-	μm	

Electrical Characteristics at $T_A = 25^{\circ}$ C, unless otherwise specified



Diode capacitance $C_{T} = f(V_{R})$

f = 1 MHz



Forward resistance $r_{\rm f} = f (I_{\rm F})$

f = 100 MHz











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